

# Zero-Drift, Single-Supply, Rail-to-Rail Input/ Output Operational Amplifiers

### **General Description**

The HM8581, HM8582 and HM8584 are single, dual and quad amplifiers featuring rail-to-rail input and output swings, which has ultralow offset, drift and bias current, All are guaranteed to operate from +2.7 V to +5 V single supply.

With an offset voltage of only 80 µV and drift of 20 nV/°C, the HM8581 is perfectly suited for applications where error sources cannot be tolerated. Temperature, position and pres-sure sensors, medical equipment and strain gage amplifiers benefit greatly from nearly zero drift over their operating temperature range. The rail-to-rail input and output swings provided by the HM858X family make both high-side and low- side sensing easy.

The HM858X series is specified for the extended industrial/automotive (-40°C to +125°C) temperature range. The HM8581 single is available in 5-lead SOT and 8-lead SOP/MSOP packages. The HM8582 dual amplifier is available in 8-lead SOP/MSOP packages. The HM8584 quad is available in narrow 14-lead SOP and 14-lead TSSOP packages.

## Applications

- **Temperature Measurements**
- **Pressure Sensors**
- **Precision Current Sensing**
- **Electronic Scales**
- Strain Gage Amplifiers
- Medical Instrumentation
- Thermocouple Amplifiers
- Handheld Test Equipment

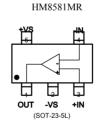
#### **Features**

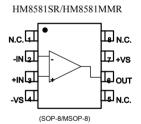
- Low Offset Voltage: 80µV (TYP)
- Rail-to-Rail Input and Output Swing
- 2.7V to 5.0V Single Supply Operation
- Voltage Gain: 145dB (TYP)
- PSRR: 115dB (TYP)
- CMRR: 110dB (TYP)
- Low Input Bias Currents: 130pA
- Low Supply Current: 450µA/Channel
- Overload Recovery Time: 0.1ms
- No External Capacitors Required
- -40°C to +125°C Operating Temperature Range
- Small Packaging:

HM8581 Available in Green SOT-23-5L, SOP8 and MSOP8

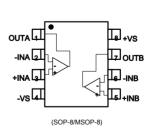
HM8582 Available in Green SOP8 and MSOP8 HM8584 Available in Green SOP14

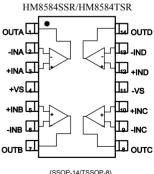
### **Package**





HM8582SR/HM8582MMR







# ■ Ordering Information

HM858 ①②③

Designator	Symbol	Description
		Product No.
	1	HM8581
1)	2	HM8582
	4	HM8584
	_	Package
	M	SOT-23-5
2	S	SOP-8
2	MM	MSOP-8
	SS	SSOP-14
	TS	TSSOP-14
	_	Device Orientation
3	R	Embossed Tape: Standard Feed
	L	Embossed Tape: Reverse Feed

# ■ Marking

HM8581MR



81----HM8581MR

A----die code

X----process code

HM8588123



HM858.---HM8581 or HM8582 or HM8584 XXXX------process code YYYYYY----lot code

# **■** Absolute Maximum Ratings

<b></b>	Supply Voltage6V
<b></b>	Input VoltageVS+0.3V—+VS+0.3V
<b></b>	Differential Input Voltage5.0V to +5.0V
<b></b>	Package Thermal Resistance @ TA = 25°C
	SOT-23-5L190°C/W
	MSOP-8216℃/W
	SOP-8125°C/W
	SSOP-14120℃/W
	TSSOP-14180℃/W
<b></b>	Storage temperature range65℃ to 150℃
<b></b>	Operating junction temperature40°C to 125°C
<b></b>	ESD Human Model4000V
<b></b>	Lead Temperature Range (Soldering 10 sec)
	260℃



# ■ Electrical Characteristics

(VS = +5V, VCM = +2.5V, VO = +2.5V, TA = +25 $^{\circ}$ C, unless otherwise noted.)

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
INPUT CHA	RACTERISTICS			•	•	•
Vos	Input Offset Voltage		_	80	100	μV
I <sub>B</sub>	Input Bias Current			100		pА
Ios	Input Offset Current			10		pA
CMRR	Common-Mode Rejection Ratio	V <sub>CM</sub> = 0V to 5V		110		dB
A <sub>VO</sub>	Large Signal Voltage Gain	$R_L = 10k\Omega V_0 = 0.3V \sim 4.7V$		145		dB
$\Delta V_{OS}/\Delta T$	Input Offset Voltage Drift			20		nV/℃
OUTPUT C	HARACTERISTICS		•			•
	Output Voltage High	RL = 100kΩ to -VS		4.998		V
$V_{OH}$		RL = 10kΩ to -VS		4.994		V
	Output Voltage Low	RL = 100kΩ to +VS		2		mV
$V_{OL}$		RL = 10kΩ to +VS		5		mV
I <sub>SC</sub>	Short Circuit Limit	RL =10Ω to -VS		43		mA
Io	Output Current			30		mA
POWER SU	PPLY		•			
PSRR	Power Supply Rejection Ratio	VS = 2.7V to 5.5V		115		dB
IQ	Quiescent Current	VO = 0V, RL = 0Ω		450		μA
DYNAMIC F	PERFORMANCE		•			•
GBP	Gain-Bandwidth Product	G = +100		1.44		MHz
SR	Slew Rate	RL = 10kΩ		0.84		V/µs
T <sub>OR</sub>	Overload Recovery Time			0.10		ms
NOISE PER	FORMANCE		•	•	•	•
e <sub>n</sub> p-p	Voltage Noise	0Hz to 10Hz		0.81		µVp-p
e <sub>n</sub>	Voltage Noise Density	f = 1kHz		49		nV/ $\sqrt{Hz}$



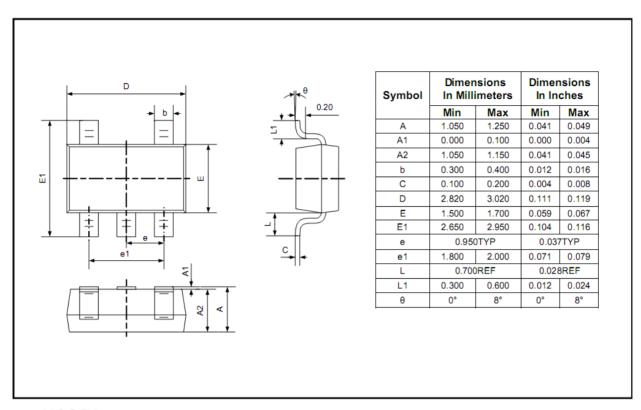
 $(VS = +2.7V, VCM = +1.35V, VO = +1.35V, TA = +25^{\circ}C, unless otherwise noted.)$ 

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
INPUT CHA	RACTERISTICS				<u>'</u>	
Vos	Input Offset Voltage			80	100	μV
I <sub>B</sub>	Input Bias Current			75		pA
I <sub>OS</sub>	Input Offset Current			5		pA
CMRR	Common-Mode Rejection Ratio	V <sub>CM</sub> = 0V to 2.7V		110		dB
A <sub>VO</sub>	Large Signal Voltage Gain	$R_L = 10k\Omega V_0 = 0.3V \sim 2.4V$		140		dB
$\Delta V_{OS}/\Delta T$	Input Offset Voltage Drift			20		nV/℃
OUTPUT CI	HARACTERISTICS		•		•	
	Output Voltage High	RL = 100kΩ to -VS		2.699		V
$V_{OH}$		RL = $10k\Omega$ to -VS		2.697		V
	Output Voltage Low	RL = 100kΩ to +VS		1		mV
$V_{OL}$		RL = $10k\Omega$ to +VS		2		mV
I <sub>SC</sub>	Short Circuit Limit	RL =10Ω to -VS		26		mA
Io	Output Current			10		mA
POWER SU	PPLY	-		•	W.	
PSRR	Power Supply Rejection Ratio	VS = 2.7V to 5.5V		115		dB
IQ	Quiescent Current	VO = 0V, RL = 0Ω		450		μΑ
DYNAMIC F	PERFORMANCE		•		•	
GBP	Gain-Bandwidth Product	G = +100		1.43		MHz
SR	Slew Rate	RL = 10kΩ		0.84		V/µs
T <sub>OR</sub>	Overload Recovery Time			0.04		ms
NOISE PER	FORMANCE	,	ı			1
e <sub>n</sub> p-p	Voltage Noise	0Hz to 10Hz		0.90		μVp-p
e <sub>n</sub>	Voltage Noise Density	f = 1kHz		53		nV/ $\sqrt{Hz}$

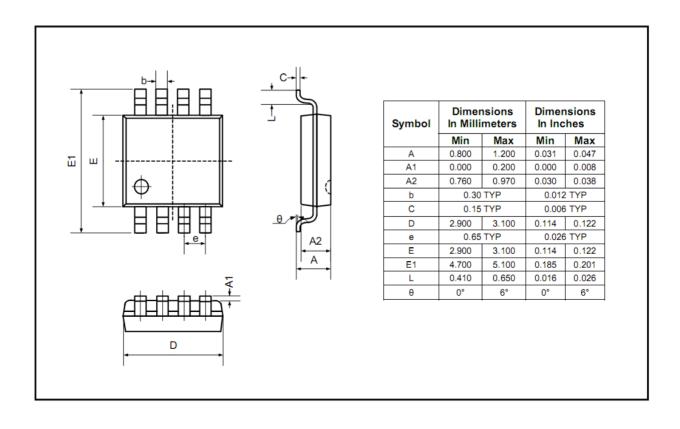


# ■ Package Information

### SOT-23-5L

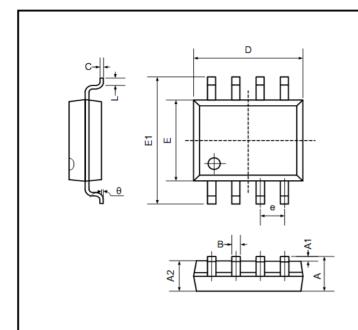


### MSOP8





### SOP8



Symbol		nsions meters	Dimensions In Inches			
	Min	Max	Min	Max		
Α	1.350	1.750	0.053	0.069		
A1	0.100	0.250	0.004	0.010		
A2	1.350	1.550	0.053	0.061 0.020 0.010		
В	0.330	0.510	0.013			
С	0.190	0.250	0.007			
D	4.780	5.000	0.188	0.197		
E	3.800	4.000	0.150	0.157		
E1	5.800	6.300	0.228	0.248		
е	1.270TYP		0.050TYP			
L	0.400	1.270	0.016	0.050		
θ	0°	8°	0°	8°		

### SOP14

